NSN 5962-01-192-0212

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Yes - demil/mli



View Online at https://aerobasegroup.com/nsn/5962-01-192-0212

Body Length:	
0.960 inches	
Body Width:	
Between 0.220 inches an	id 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dissip	ation Rating:
715.0 milliwatts	
Operating Tempurature	Range:
-55.0/+125.0 degrees cel	sius
Storage Tempurature R	ange:
-65.0/+150.0 degrees cel	sius
Features Provided:	
Hermetically sealed and I	burn in and schottky and programmable and monolithic and bipolar
Inclosure Material:	
Ceramic	
Inclosure Configuration	1:
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	;
Input Circuit Pattern:	
12 input	
Case Outline Source Ar	nd Designator:
D-6 mil-m-38510	
Terminal Surface Treat	nent:
Solder	
Voltage Rating And Typ	e Per Characteristic:
5.5 volts power source	
Time Rating Per Chacte	eristic:
125.00 nanoseconds pro	opagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low leve
output	
Memory Device Type:	
Rom	
Test Data Document:	
96906-mil-std-883 standa	ard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Qua	intity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Fiig: A458a0

